2SK806

Silicon N-channel Power F-MOS FET

■ Features

- Low ON resistance R_{DS} (on) : R_{DS} (on) = 1.8 Ω (typ.)
- High switching rate : t_f=40ns (typ.)
- No secondary breakdown
- High breakdown voltage

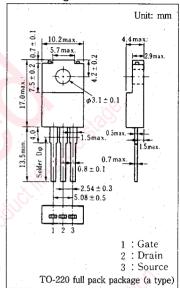
Application

- No contact relay
- Solenoid drive
- Motor drive
- Control equipment
- Switching power source

■ Absolute Maximum Ratings (Tc=25°C)

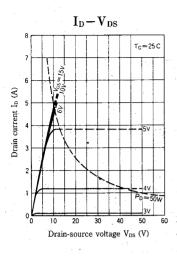
Item		Symbol	Value	Unit V	
Drain-source voltage		V _{DSS}	600		
Gate-source voltage		V_{GSS}	±20	V	
Drain current	DC	I _D	3	110	
	Peak-to-peak value	I_{DP}	6	O A	
Power dissipation	Tc=25℃	n	50	777	
	Ta=25℃	P_{D}	2.0	W	
Channel temperature		T _{ch}	150	°C	
Storage temperature		Tstg	-55~+150	°C	

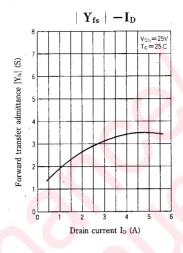
■ Package Dimensions

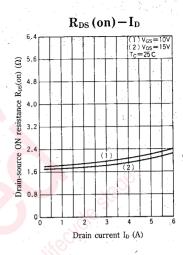


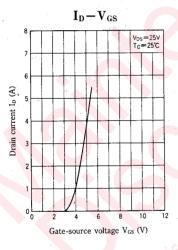
■ Electrical Characteristics (Tc=25°C)

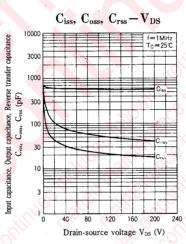
Item	Symbol	Condition	min.	typ.	max.	Unit
Drain current	I_{DSS}	$V_{DS} = 480 \text{V}, \ V_{GS} = 0$			0.1	mA
Gate-source current	I_{GSS}	$V_{GS} = \pm 20 V, V_{DS} = 0$			±1	μΑ
Drain-source voltage	V_{DSS}	$I_D = 1 \text{ mA}, V_{GS} = 0$	600			v
Gate threshold voltage	V_{th}	$V_{DS}=25V$, $I_D=1mA$	1		5	V
Drain-source ON resistance	R _{DS} (on)	$V_{GS} = 10V, I_D = 2A$,	1.8	2.7	Ω
Forward transfer admittance	Yfs	$V_{DS}=25V$, $I_D=2A$	1.5	2.5		S
Input capacitance	Ciss	$V_{DS} = 20V, V_{GS} = 0, f = 1MHz$		600		рF
Output capacitance	Coss			110		pF
Reverse transfer capacitance	Crss			45	,	pF
Turn-on time	ton	V -10V I -24	7.7	35		ns
Fall time	. t _{f.}	$V_{GS} = 10V, I_D = 2A$ $V_{DD} = 150V, R_L = 75 \Omega$,	40		ns
Delay time	t d (off)			120		ns

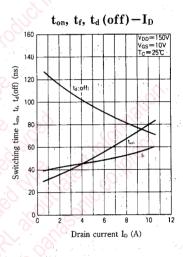


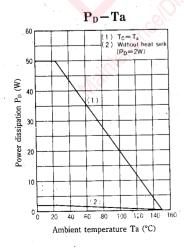


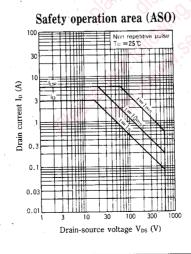


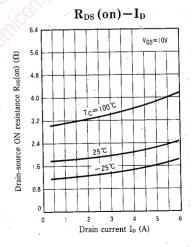












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